TOSHIBA Field Effect Transistor Silicon N-Channel Dual Gate MOS Type

3SK232

TV Tuner, UHF RF Amplifier Applications

Unit: mm

• Superior cross modulation performance.

• Low reverse transfer capacitance.: $C_{rss} = 20 \text{ fF (typ.)}$

• Low noise figure.: NF = 1.5dB (typ.)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V _{DS}	12.5	V
Gate 1-source voltage	V _{G1S}	±8	V
Gate 2-source voltage	V _{G2S}	±8	V
Drain current	I _D	30	mA
Drain power dissipation	P _D	150	mW
Channel temperature	T _{ch}	125	°C
Storage temperature range	T _{stg}	-55~125	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the

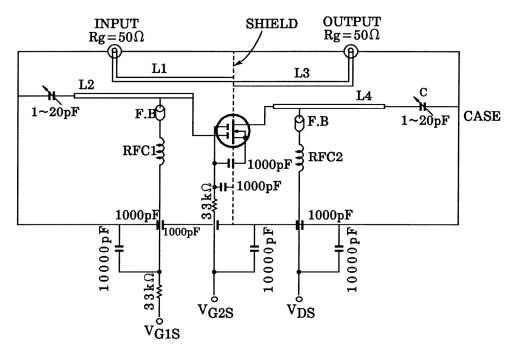
Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

1. GATE 1 2. GATE 2 3. DRAIN 4. SOURCE 1. TOSHIBA 2.9-0.3 0.85 1.00

Weight: 0.013 g (typ.)

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate 1 leakage current	I _{G1SS}	$V_{DS} = 0$, $V_{G1S} = \pm 6$ V, $V_{G2S} = 0$	_	_	±50	nA
Gate 2 leakage current	I _{G2SS}	$V_{DS} = 0$, $V_{G1S} = 0$, $V_{G2S} = \pm 6 \text{ V}$	_	_	±50	nA
Drain-source voltage	V (BR) DSX	$V_{G1S} = -0.5 \text{ V}, V_{G2S} = -0.5 \text{ V}$ $I_D = 100 \mu\text{A}$	12.5	_	_	٧
Drain current	I _{DSS}	$V_{DS} = 6 \text{ V}, V_{G2S} = 4.5 \text{ V}, V_{G1S} = 0 \text{ V}$	_	_	0.1	mA
Gate 1-source cut-off voltage	V _{G1S} (OFF)	$V_{DS} = 6 \text{ V}, V_{G2S} = 4.5 \text{ V}, I_D = 100 \mu A$	0.4	0.9	1.4	V
Gate 2-source cut-off voltage	V _{G2S} (OFF)	$V_{DS} = 6 \text{ V}, V_{G1S} = 4.0 \text{ V}, I_D = 100 \mu A$	0.5	1.0	1.5	V
Forward transfer admittance	Yfs	$V_{DS} = 6 \text{ V}, V_{G2S} = 4.5 \text{ V}, I_D = 10 \text{ mA}$ f = 1 kHz	17	21	_	mS
Input capacitance	C _{iss}	$V_{DS} = 6 \text{ V}, V_{G2S} = 4.5 \text{ V}, I_D = 10 \text{ mA}$	0.9	1.5	2.1	pF
Reverse transfer capacitance	C _{rss}	f = 1 MHz	_	20	40	fF
Power gain	G _{ps}	$V_{DS} = 6 \text{ V}, V_{G2S} = 4.5 \text{ V}, I_D = 10 \text{ mA}$	18	20	_	dB
Noise figure	NF	f = 800 MHz (Figure 1)	_	1.5	2.5	dB



L1~L4: φ0.8 mm silver plated copper wire

C: Air trimmer TTA25A200A (MURATA Manufacturing, Co., Ltd.)

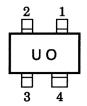
RFC 1: $\phi 0.35$ mm copper wire 3 mm ID, 7 T

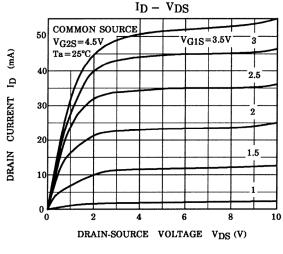
RFC 2: $\phi 0.35$ mm copper wire 3 mm ID, 10 T

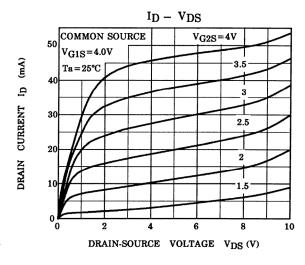
Figure 1 800 MHz G_{ps}, NF Test Circuit

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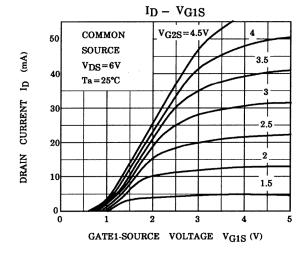
Marking

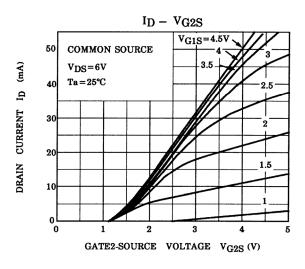


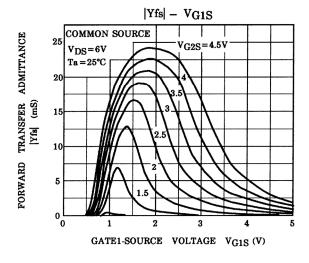


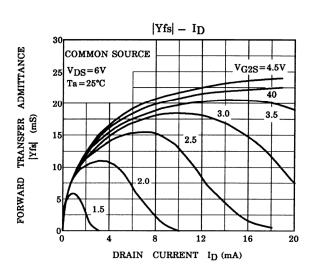


 $V_{G2S} = 4.5V$ Ta = 25°C









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20070701-EN GENERAL

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